

MR26V6455J

2M-Word \times 32-Bit or 4M-Word \times 16-Bit Page Mode P2ROM

FEATURES

- \cdot 2,097,152-word \times 32-bit / 4,194,304-word \times 16-bit electrically switchable configuration
- · Page size of 8-word x 32-Bit or 16-word x 16-Bit
- · 3.0 V to 3.6 V power supply

·Random Access time
 ·Page Access time
 · Operating current
 · Standby current
 · Standby current

100 ns MAX
30ns MAX
100 mA MAX
20 μA MAX

- · Input/Output TTL compatible
- · Three-state output

PACKAGES

· MR26V6455J-xxxMB 70-pin plastic SSOP (P-SSOP70-500-0.80-EK-MC)

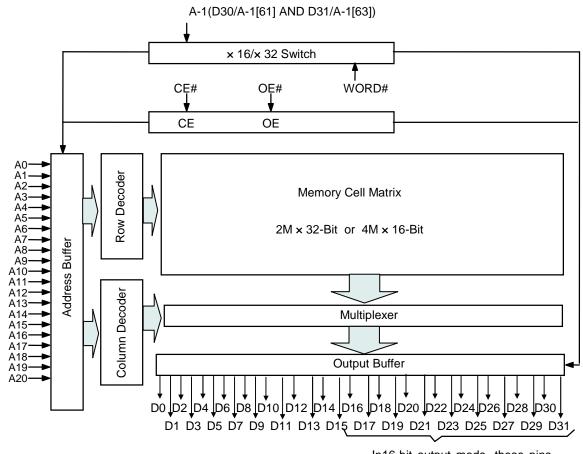
P2ROM ADVANCED TECHNOLOGY

P2ROM stands for Production Programmed ROM. This exclusive LAPIS Semiconductor technology utilizes factory test equipment for programming the customers code into the P2ROM prior to final production testing. Advancements in this technology allows production costs to be equivalent to MASKROM and has many advantages and added benefits over the other non-volatile technologies, which include the following;

- Short lead time, since the P2ROM is programmed at the final stage of the production process, a large P2ROM inventory "bank system" of un-programmed packaged products are maintained to provide an aggressive lead-time and minimize liability as a custom product.
- No mask charge, since P2ROMs do not utilize a custom mask for storing customer code, no mask charges apply.
- No additional programming charge, unlike Flash and OTP that require additional programming and handling costs, the P2ROM already has the code loaded at the factory with minimal effect on the production throughput. The cost is included in the unit price.
- Custom Marking is available at no additional charge.

| PIN CONFIGURATION (TOP VIEW) | | | | | | |
|------------------------------|--------------------|--|--|--|--|--|
| A0 1 | 70 NC | | | | | |
| A1 2 | 69 NC | | | | | |
| A2 3 | 68 A20 | | | | | |
| A3 4 | 67 WORD# | | | | | |
| A4 5 | 66 OE# | | | | | |
| A5 6 | 65 CE# | | | | | |
| Vcc 7 | 64 Vss | | | | | |
| D0 8 | 63 D31/ A-1 | | | | | |
| D16 9 | 62 D15 | | | | | |
| D1 10 | 61 D30/ A-1 | | | | | |
| D17 11 | 60 D14 | | | | | |
| Vss 12 | 59 Vss | | | | | |
| Vcc 13 | 58 Vcc | | | | | |
| D2 14 | 57 D29 | | | | | |
| D18 15 | 56 D13 | | | | | |
| D3 16 | 55 D28 | | | | | |
| D19 17 | 54 D12 | | | | | |
| D4 18 | 53 D27 | | | | | |
| D20 19 | 52 D11 | | | | | |
| D5 20 | 51 D26 | | | | | |
| D21 21 | 50 D10 | | | | | |
| Vss 22 | 49 Vss | | | | | |
| Vcc 23 | 48 Vcc | | | | | |
| D6 24 | 47 D25 | | | | | |
| D22 25 | 46 D9 | | | | | |
| D7 26 | 45 D24 | | | | | |
| D23 27 | 44 D8 | | | | | |
| Vss 28 | 43 Vcc | | | | | |
| A6 29 | 42 A19 | | | | | |
| A7 30 | 41 A18 | | | | | |
| A8 31 | 40 A17 | | | | | |
| A9 32 | 39 A16 | | | | | |
| A1033 | 38 A15 | | | | | |
| A11 34 | 37 A14 | | | | | |
| A1235 | 36 A13 | | | | | |
| | // | | | | | |

BLOCK DIAGRAM



In16-bit output mode, these pins are placed in a high-Z state and pin D31,D30 functions as the A-1 address pin.

PIN DESCRIPTIONS

| Pin name | Functions |
|-------------------|-----------------------------|
| D31 / A-1,D30/A-1 | Data output / Address input |
| A0 to A20 | Address inputs |
| D0 to D29 | Data outputs |
| CE# | Chip enable input |
| OE# | Output enable input |
| WORD# | Word -Byte select input |
| V _{CC} | Power supply voltage |
| V_{SS} | Ground |

FUNCTION TABLE

| Mode | CE# | OE# | WORD# | V _{CC} | D0 to D15 | D16 to D29 | D30/A-1,D31/A-1 |
|------------------|-------|-----|-------|-----------------|------------------|------------|-----------------|
| Read (32-Bit) | L | Ш | Н | | | D_OUT | |
| Read (16Bit) | L | Ш | L | | D _{OUT} | Hi–Z | L/H |
| Output disable | | L H | Н | 3.3 V | | | |
| Output disable L | _ | | L | 3.3 V | | Hi–Z | * |
| Ctondhy | | | Н | | | Hi–Z | |
| Standby | H * | L | | | ⊓I – ∠ | * | |

^{*:} Don't Care (H or L)

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Condition | Value | Unit |
|----------------------------------|-----------------|-----------------------------|------------------------------|------|
| Operating temperature under bias | Та | | 0 to 70 | °C |
| Storage temperature | Tstg | _ | -55 to 125 | °C |
| Input voltage | VI | | -0.5 to V _{CC} +0.5 | V |
| Output voltage | Vo | relative to V _{SS} | -0.5 to V _{CC} +0.5 | V |
| Power supply voltage | V _{CC} | | -0.5 to 5 | V |
| Power dissipation per package | P _D | Ta = 25°C | 1.0 | W |
| Output short circuit current | los | _ | 10 | mA |

RECOMMENDED OPERATING CONDITIONS

 $(Ta = 0 \text{ to } 70^{\circ}C)$

| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
|--------------------------------------|-----------------|--|--------|------|-----------------------|------|
| V _{CC} power supply voltage | Vcc | | 3.0 | _ | 3.6 | V |
| Input "H" level | V _{IH} | $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ | 2.2 | _ | V _{CC} +0.5* | V |
| Input "L" level | V_{IL} | | -0.5** | _ | 0.6 | V |

Voltage is relative to V_{SS} .

- * : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.
- **: -1.5V(Min.) when pulse width of undershoot is less than 10ns.

PIN CAPACITANCE

 $(V_{CC} = 3.3 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}, \text{ f} = 1 \text{ MHz})$

| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
|-----------|------------------|----------------------|------|------|------|------|
| Input | C _{IN1} | V ₁ = 0 V | _ | _ | 20 | |
| WORD# | C _{IN2} | V ₁ = U V | _ | _ | 400 | pF |
| Output | Соит | $V_0 = 0 V$ | _ | _ | 20 | |

ELECTRICAL CHARACTERISTICS

DC Characteristics

 $(V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}, \text{Ta} = 0 \text{ to } 70^{\circ}\text{C})$

| (100 = 0.0 1 = 0.0 1, 14 = 0.0 | | | | | | | _ 0 (0 / 0 0) |
|---|-------------------|---|----------------------|--------|------|-----------------------|--------------------------|
| Parameter | Symbol | Condition | | Min. | Тур. | Max. | Unit |
| Input leakage current | I _{LI} | $V_1 = 0$ to V_{CC} | | _ | _ | 10 | μΑ |
| Output leakage current | I _{LO} | V _O = 0 | 0 to V _{CC} | _ | _ | 10 | μΑ |
| V _{CC} power supply current | Iccsc | CE# = V _{CC} | | _ | _ | 20 | μΑ |
| (Standby) | Iccst | CE# = V _{IH} | | _ | _ | 1 | mA |
| V _{CC} power supply current (Read) | I _{CCA1} | CE# = V _{IL} OE#= V _{IH} | tc = 5MHz | _ | _ | 100 | mA |
| Input "H" level | V _{IH} | _ | | 2.2 | _ | V _{CC} +0.5* | V |
| Input "L" level | V_{IL} | _ | | -0.5** | _ | 0.6 | V |
| Output "H" level | V _{OH} | $I_{OH} = -2 \text{ mA}$ | | 2.4 | _ | _ | V |
| Output "L" level | V _{OL} | $I_{OL} = 2 \text{ mA}$ | | _ | _ | 0.4 | V |

Voltage is relative to V_{SS} .

- * : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.
- **: -1.5V(Min.) when pulse width of undershoot is less than 10ns.

AC Characteristics

 $(V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}, \text{ Ta} = 0 \text{ to } 70^{\circ}\text{C})$

| Parameter | Symbol | Condition | Min. | Max. | Unit |
|---------------------|------------------|-----------------------------|------|------|------|
| Address cycle time | t _C | 1 | 100 | 1 | ns |
| Address access time | t _{ACC} | $CE# = OE# = V_{IL}$ | | 100 | ns |
| Page cycle time | t _{PC} | | 30 | | ns |
| Page access time | t _{PAC} | CE# = OE# = V _{IL} | | 30 | ns |
| CE# access time | t _{CE} | OE# = V _{IL} | | 100 | ns |
| OE# access time | t _{OE} | CE# = V _{IL} | | 30 | ns |
| Output disable time | t _{CHZ} | OE# = V _{IL} | 0 | 20 | ns |
| Output disable time | t _{OHZ} | $CE# = V_{IL}$ | 0 | 20 | ns |
| Output hold time | t _{OH} | $CE# = OE# = V_{IL}$ | 0 | _ | ns |

Measurement conditions

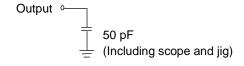
Input signal level 0 V/3 V

Input timing reference level 1/2Vcc

Output load 50 pF

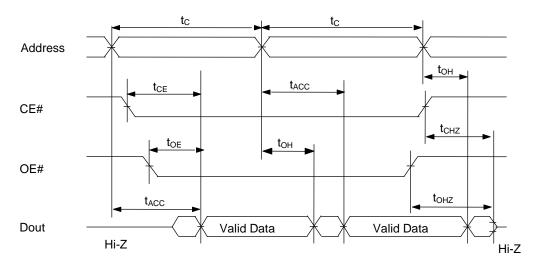
Output timing reference level 1/2Vcc

Output load

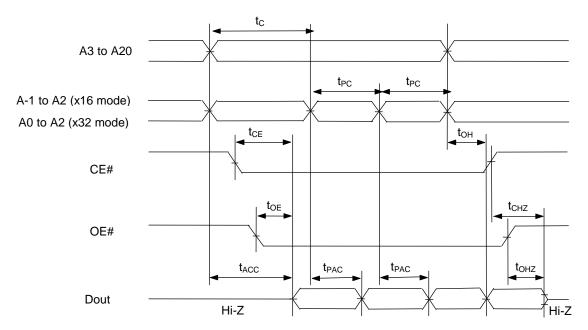


TIMING CHART (READ CYCLE)

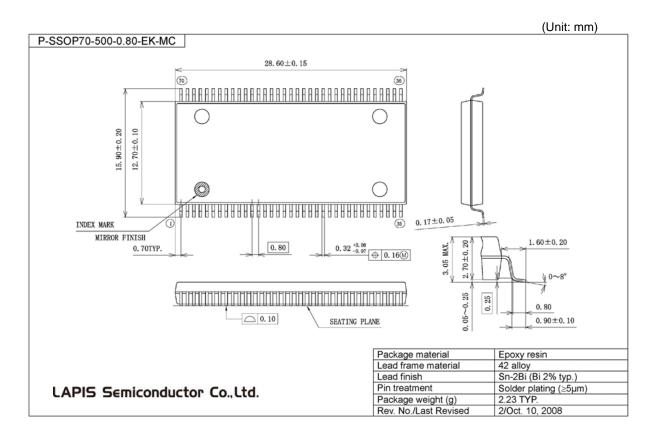
Random Access Mode Read Cycle



Page Access Mode Read Cycle



PACKAGE DIMENSIONS



Notes for Mounting the Surface Mount Type Package

The surface mount type packages are very susceptible to heat in reflow mounting and humidity absorbed in storage.

Therefore, before you perform reflow mounting, contact ROHM's responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

REVISION HISTORY

| Document | | Page | | | |
|--------------------------------|--------------|---------------------|--------------------|--|--|
| No. | Date | Previous Edition | Current Edition | Description | |
| FEDR26V6455J-02-01 | Oct.30, 2007 | - | ı | Final edition 1 | |
| FFDD26\/6455 002 02 | Oct 1, 2009 | 1 | 1 | Deleted "Pin Compatible with Mask ROM". | |
| FEDR26V6455J-002-02 Oct.1, 200 | | _ | _ | Changed company logo and name to OKI SEMICONDUCTOR | |

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